

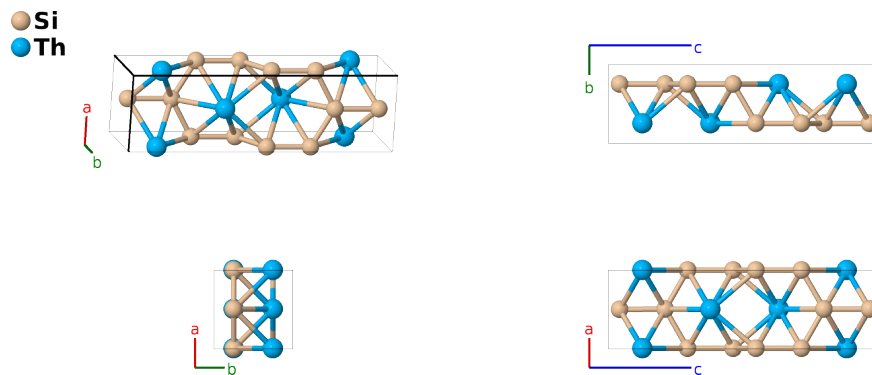
α -ThSi₂ (C_c) Structure: A2B_tI12_141_e_a-002

This structure originally had the label A2B_tI12_141_e_a.ThSi2. Calls to that address will be redirected here.

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<https://aflow.org/p/NF8F>

https://aflow.org/p/A2B_tI12_141_e_a-002



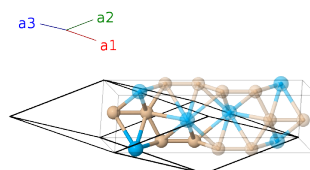
Prototype	ThSi ₂
AFLOW prototype label	A2B_tI12_141_e_a-002
<i>Strukturbericht</i> designation	C_c
ICSD	77320
Pearson symbol	tI12
Space group number	141
Space group symbol	$I4_1/amd$
AFLOW prototype command	<code>aflow --proto=A2B_tI12_141_e_a-002 --params=a, c/a, z₂</code>

Other compounds with this structure

CdSi₂, DySi₂, GdGe₂, LaGe₂, LaSi₂, NdGe₂, NpSi₂, PrGe₂, PuGe₂, PuSi₂, SmGe₂, α -USi₂

Body-centered Tetragonal primitive vectors

$$\begin{aligned} \mathbf{a}_1 &= -\frac{1}{2}a \hat{x} + \frac{1}{2}a \hat{y} + \frac{1}{2}c \hat{z} \\ \mathbf{a}_2 &= \frac{1}{2}a \hat{x} - \frac{1}{2}a \hat{y} + \frac{1}{2}c \hat{z} \\ \mathbf{a}_3 &= \frac{1}{2}a \hat{x} + \frac{1}{2}a \hat{y} - \frac{1}{2}c \hat{z} \end{aligned}$$



Basis vectors

	Lattice coordinates	=	Cartesian coordinates	Wyckoff position	Atom type
\mathbf{B}_1	$= \frac{7}{8} \mathbf{a}_1 + \frac{1}{8} \mathbf{a}_2 + \frac{3}{4} \mathbf{a}_3$	=	$\frac{3}{4} a \hat{\mathbf{y}} + \frac{1}{8} c \hat{\mathbf{z}}$	(4a)	Th I
\mathbf{B}_2	$= \frac{1}{8} \mathbf{a}_1 + \frac{7}{8} \mathbf{a}_2 + \frac{1}{4} \mathbf{a}_3$	=	$\frac{1}{2} a \hat{\mathbf{x}} - \frac{1}{4} a \hat{\mathbf{y}} + \frac{3}{8} c \hat{\mathbf{z}}$	(4a)	Th I
\mathbf{B}_3	$= \left(z_2 + \frac{1}{4}\right) \mathbf{a}_1 + z_2 \mathbf{a}_2 + \frac{1}{4} \mathbf{a}_3$	=	$\frac{1}{4} a \hat{\mathbf{y}} + cz_2 \hat{\mathbf{z}}$	(8e)	Si I
\mathbf{B}_4	$= z_2 \mathbf{a}_1 + \left(z_2 + \frac{1}{4}\right) \mathbf{a}_2 + \frac{3}{4} \mathbf{a}_3$	=	$\frac{1}{2} a \hat{\mathbf{x}} + \frac{1}{4} a \hat{\mathbf{y}} + c \left(z_2 - \frac{1}{4}\right) \hat{\mathbf{z}}$	(8e)	Si I
\mathbf{B}_5	$= -\left(z_2 - \frac{3}{4}\right) \mathbf{a}_1 - z_2 \mathbf{a}_2 + \frac{3}{4} \mathbf{a}_3$	=	$\frac{3}{4} a \hat{\mathbf{y}} - cz_2 \hat{\mathbf{z}}$	(8e)	Si I
\mathbf{B}_6	$= -z_2 \mathbf{a}_1 - \left(z_2 - \frac{3}{4}\right) \mathbf{a}_2 + \frac{1}{4} \mathbf{a}_3$	=	$\frac{1}{2} a \hat{\mathbf{x}} - \frac{1}{4} a \hat{\mathbf{y}} - c \left(z_2 - \frac{1}{4}\right) \hat{\mathbf{z}}$	(8e)	Si I

References

- [1] G. Brauer and A. Mitius, *Die Kristallstruktur des Thoriumsilicids $ThSi_2$* , Z. Anorganische und Allgemeine Chemie **249**, 325–339 (1942), doi:10.1002/zaac.19422490401.

Found in

- [1] W. B. Pearson, *The Crystal Chemistry and Physics of Metals and Alloys* (Wiley Interscience, New York, London, Sydney, Toronto, 1972).